Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	56800EX
Core Size	32-Bit Single-Core
Speed	60MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	Brown-out Detect/Reset, DMA, LVD, POR, PWM, WDT
Number of I/O	54
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 16x12b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc56f84462vlh

- 32-bit arithmetic and logic multi-bit shifter
- Four 36-bit accumulators, including extension bits
- Parallel instruction set with unique DSP addressing modes
- Hardware DO and REP loops
- Bit reverse address mode, effectively supporting DSP and Fast Fourier Transform algorithms
- Full shadowing of the register stack for zero-overhead context saves and restores: nine shadow registers corresponding to the R0, R1, R2, R3, R4, R5, N, N3, and M01 address registers
- Instruction set supporting both DSP and controller functions
- Controller-style addressing modes and instructions for compact code
- Enhanced bit manipulation instruction set
- Efficient C compiler and local variable support
- Software subroutine and interrupt stack with depth limited only by memory
- Priority level setting for interrupt levels
- JTAG/Enhanced On-Chip Emulation (OnCE) for unobtrusive, real-time debugging that is independent of processor speed

1.3 Operation Parameters

- Up to 60 MHz operation at -40 °C to 105 °C ambient temperature
- Single 3.3 V power supply
- Supply range: V_{DD} - V_{SS} = 2.7 V to 3.6 V, V_{DDA} - V_{SSA} = 2.7 V to 3.6 V

1.4 On-Chip Memory and Memory Protection

- Modified dual Harvard architecture permits as many as three simultaneous accesses to program and data memory
- Internal flash memory with security and protection to prevent unauthorized access
- Memory resource protection (MRP) unit to protect supervisor programs and resources from user programs
- Programming code can reside in flash memory during flash programming
- The dual-ported RAM controller supports concurrent instruction fetches and data accesses, or dual data accesses, by the DSC core.
  - Concurrent accesses provide increased performance.
  - The data and instruction arrive at the core in the same cycle, reducing latency.
- On-chip memory
  - Up to 128 KW program/data flash memory
  - Up to 16 KW dual port data/program RAM

1.6.13 Phase Locked Loop

- Wide programmable output frequency: 240 MHz to 400 MHz
- Input reference clock frequency: 8 MHz to 16 MHz
- Detection of loss of lock and loss of reference clock
- Ability to power down

1.6.14 Clock sources

1.6.14.1 On-Chip Oscillators

- Tunable 8 MHz relaxation oscillator with 400 kHz at standby mode (divide-by-two output)
- 32 kHz low frequency clock as secondary clock source for COP, EWM, PIT

1.6.14.2 Crystal Oscillator

- Support for both high ESR crystal oscillator (greater than 100-ohm ESR) and ceramic resonator
- 4 MHz to 16 MHz operating frequency

1.6.15 Cyclic Redundancy Check (CRC) Generator

- Hardware 16/32-bit CRC generator
- High-speed hardware CRC calculation
- Programmable initial seed value
- Programmable 16/32-bit polynomial
- Error detection for all single, double, odd, and most multi-bit errors
- Option to transpose input data or output data (CRC result) bitwise or bytewise,[1] which is required for certain CRC standards
- Option for inversion of final CRC result

1.6.16 General Purpose I/O (GPIO)

- 5 V tolerance
- Individual control of peripheral mode or GPIO mode for each pin
- Programmable push-pull or open drain output
- Configurable pullup or pulldown on all input pins

1. A bytewise transposition is not possible when accessing the CRC data register via 8-bit accesses. In this case, user software must perform the bytewise transposition.

- All pins except JTAG and RESETB pins default to be GPIO inputs
- 2 mA / 9 mA source/sink capability
- Controllable output slew rate

1.7 Block Diagrams

The 56800EX core is based on a modified dual Harvard-style architecture consisting of three execution units operating in parallel, allowing as many as six operations per instruction cycle. The MCU-style programming model and optimized instruction set allow straightforward generation of efficient, compact DSP and control code. The instruction set is also highly efficient for C compilers to enable rapid development of optimized control applications.

The device's basic architecture appears in Figure 1 and Figure 2. Figure 1 illustrates how the 56800EX system buses communicate with internal memories and the IPBus interface and the internal connections among each unit of the 56800EX core. Figure 2 shows the peripherals and control blocks connected to the IPBus bridge. See the specific device's Reference Manual for details.

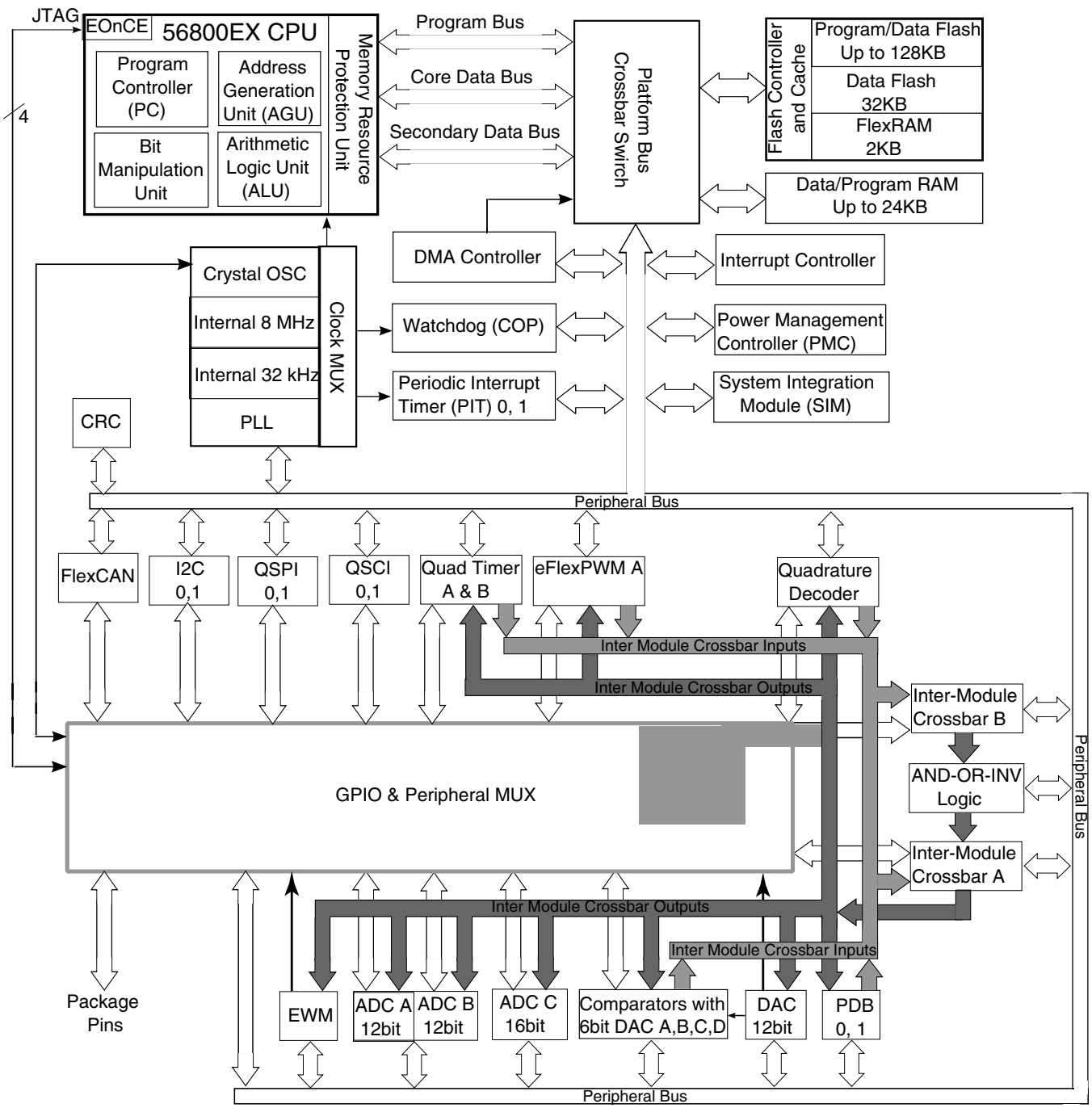

Figure 2. System Diagram

2 Signal groups

The input and output signals of the MC56F84xxx are organized into functional groups, as detailed in Table 2.

Table 2. Functional Group Pin Allocations

Functional Group	Number of Pins in 48LQFP	Number of Pins in 64LQFP	Number of Pins in 80LQFP	Number of Pins in 100LQFP
Power Inputs (V_{DD}, V_{DDA}, V_{CAP})	5	6	6	6
Ground (V_{SS}, V_{SSA})	4	4	4	4
Reset	1	1	1	1
eFlexPWM ports, not including fault pins	6	9	N/A	N/A
Queued Serial Peripheral Interface (QSPI) ports	5	6	8	15
Queued Serial Communications Interface (QSCI) ports	6	9	13	15
Inter-Integrated Circuit (I^2C) interface ports	4	6	6	6
12-bit Analog-to-Digital Converter (Cyclic ADC) inputs	10	16	16	16
16-bit Analog-to-Digital Converter (SAR ADC) inputs	2	8	10	16
Analog Comparator inputs/outputs	10/4	13/6	13/6	16/6
12-bit Digital-to-Analog output	1	1	1	1
Quad Timer Module (TMR) ports	6	9	11	13
Controller Area Network (FlexCAN)	2	2	2	2
Inter-Module Crossbar inputs/outputs	12/2	16/6	19/17	25/19
Clock inputs/outputs	2/2	2/2	2/3	2/3
JTAG / Enhanced On-Chip Emulation (EOnCE)	4	4	4	4

3 Ordering parts

3.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to www.freescale.com and perform a part number search for the following device numbers: MC56F84

4 Part identification

4.4 Example

This is an example part number: MC56F84789VLL

5 Terminology and guidelines

5.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

5.1.1 Example

This is an example of an operating requirement, which you must meet for the accompanying operating behaviors to be guaranteed:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	0.9	1.1	V

5.2 Definition: Operating behavior

An *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

5.2.1 Example

This is an example of an operating behavior, which is guaranteed if you meet the accompanying operating requirements:

Symbol	Description	Min.	Max.	Unit
I_{WP}	Digital I/O weak pullup/ pulldown current	10	130	µA

5.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

5.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

5.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

- *Operating ratings* apply during operation of the chip.
- *Handling ratings* apply when the chip is not powered.

5.4.1 Example

This is an example of an operating rating:

Symbol	Description	Min.	Max.	Unit
V_{DD}	1.0 V core supply voltage	–0.3	1.2	V

Absolute maximum ratings in Table 4 are stress ratings only, and functional operation at the maximum is not guaranteed. Stress beyond these ratings may affect device reliability or cause permanent damage to the device.

Unless otherwise stated, all specifications within this chapter apply over the temperature range of -40°C to 105°C ambient temperature over the following supply ranges: VSS = VSSA = 0 V, VDD = VDDA = 3.0 V to 3.6 V, CL ≤ 50 pF, f_{OP} = 60 MHz.

CAUTION

This device contains protective circuitry to guard against damage due to high static voltage or electrical fields. However, normal precautions are advised to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate voltage level.

7.2 AC Electrical Characteristics

Tests are conducted using the input levels specified in Table 7. Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured between the 10% and 90% points, as shown in Figure 3.

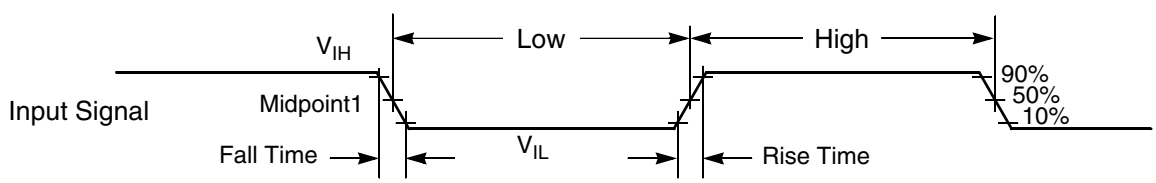

Figure 3. Input Signal Measurement References

Figure 4 shows the definitions of the following signal states:

- Active state, when a bus or signal is driven, and enters a low impedance state
- Tri-stated, when a bus or signal is placed in a high impedance state
- Data Valid state, when a signal level has reached V_{OL} or V_{OH}
- Data Invalid state, when a signal level is in transition between V_{OL} and V_{OH}

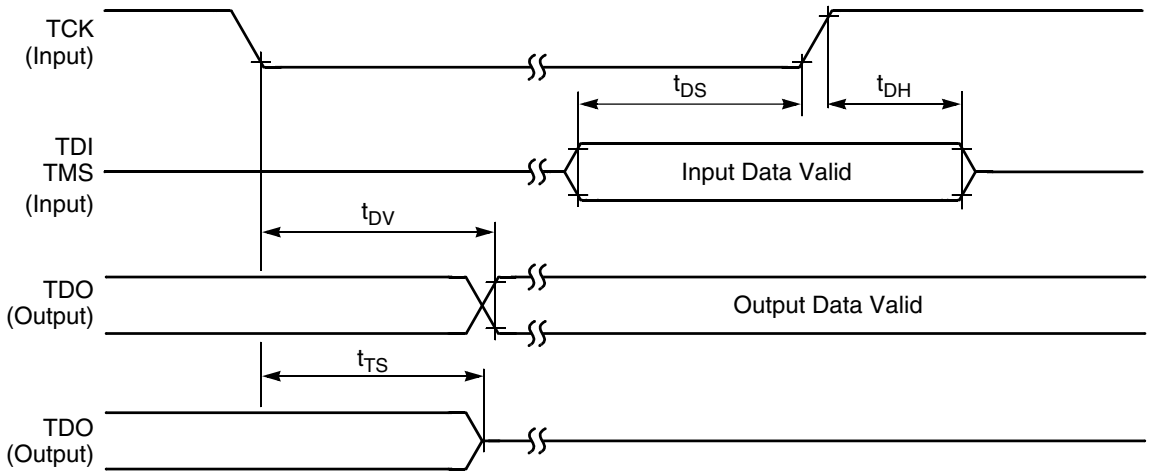

Figure 6. Test Access Port Timing Diagram

8.2 System modules

8.2.1 Voltage Regulator Specifications

The regulator supplies approximately 1.2 V to the MC56F84xxx's core logic. This regulator requires an external 2.2 µF capacitor on each V_{CAP} pin for proper operation. Ceramic and tantalum capacitors tend to provide better performance tolerances. The output voltage can be measured directly on the V_{CAP} pin. The specifications for this regulator are shown in Table 16.

Table 16. Regulator 1.2 V Parameters

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage[1]	V_{CAP}	—	1.22	—	V
Short Circuit Current[2]	I_{SS}	—	600	TBD	mA
Short Circuit Tolerance (V_{CAP} shorted to ground)	T_{RSC}	—	—	30	Minutes

1. Value is after trim
2. Guaranteed by design

Table 17. Bandgap Electrical Specifications

Characteristic	Symbol	Min	Typ	Max	Unit
Reference Voltage (after trim)	V_{REF}	—	1.21	—	V

8.3 Clock modules

8.3.3 External Crystal or Resonator Requirement

Table 20. Crystal or Resonator Requirement

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency of operation	f_{XOSC}	4	8	16	MHz

8.3.4 Relaxation Oscillator Timing

Table 21. Relaxation Oscillator Electrical Specifications

Characteristic	Symbol	Min	Typ	Max	Unit
8 MHz Output Frequency[1] RUN Mode • 0°C to 105°C • -40°C to 105°C Standby Mode (IRC trimmed @ 8 MHz) • -40°C to 105°C		 7.84 7.76 TBD	 8 8 TBD	 8.16 8.24 TBD	 MHz kHz
8 MHz Frequency Variation RUN Mode Due to temperature • 0°C to 105°C • -40°C to 105°C Standby Mode			 +/-1.5 +/- 1.5 Unspecified	 +/-2 +/-3	 %
32 kHz Output Frequency[2] RUN Mode • -40°C to 105°C		 TBD	 32	 TBD	 kHz
32 kHz Output Frequency Variation RUN Mode Due to temperature • -40°C to 105°C			 +/-2.5	 +/-4	 %
Stabilization Time • 8 MHz output[3] • 32 kHz output[4]	tstab		 0.12 14.4	 0.4 16.2	 µs
Output Duty Cycle		48	50	52	%

1. Frequency after application of 8 MHz trim
2. Frequency after application of 32 kHz trim
3. Standby to run mode transition
4. Power down to run mode transition

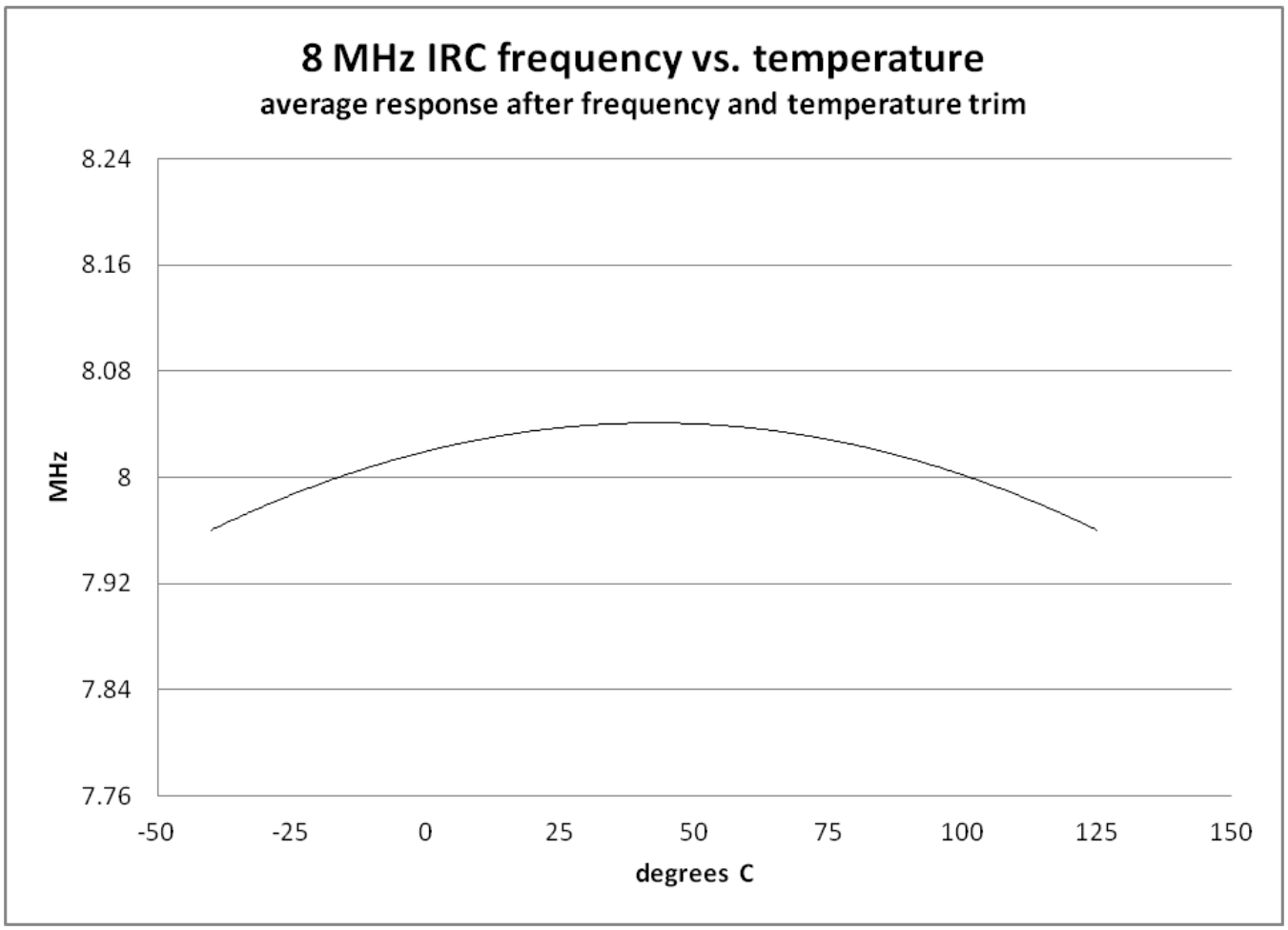

Figure 8. Relaxation Oscillator Temperature Variation (Typical) After Trim (Preliminary)

8.4 Memories and memory interfaces

8.4.1 Flash Memory Characteristics

Table 22. Flash Timing Parameters

Characteristic	Symbol	Min	Typ	Max	Unit
Longword Program high-voltage time[1]	thvpgm4	—	63	143	µs
Sector Erase high-voltage time [2]	thversscr	—	13	113	ms
Erase Block high-voltage time for 256 KB	thversblk256k	—	52	452	ms

1. There is additional overhead that is part of the programming sequence. See the device Reference Manual for detail.
2. Specifies page erase time.

8.5.2 16-bit SAR ADC electrical specifications

8.5.2.1 16-bit ADC operating conditions

Table 26. 16-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ.[1]	Max.	Unit	Notes
V_{DDA}	Supply voltage	Absolute	2.7	—	3.6	V	
ΔV_{DDA}	Supply voltage	Delta to V_{DD} (V_{DD}-V_{DDA})	-100	0	+100	mV	2
ΔV_{SSA}	Ground voltage	Delta to V_{SS} (V_{SS}-V_{SSA})	-100	0	+100	mV	2
V_{REFH}	ADC reference voltage high	Absolute	V_{DDA}	V_{DDA}	V_{DDA}	V	3
V_{REFL}	ADC reference voltage low	Absolute	V_{SSA}	V_{SSA}	V_{SSA}	V	4
V_{ADIN}	Input voltage		V_{SSA}	—	V_{DDA}	V	
C_{ADIN}	Input capacitance	• 16 bit modes • 8/10/12 bit modes	— —	8 4	10 5	pF	
R_{ADIN}	Input resistance		—	2	5	kΩ	
R_{AS}	Analog source resistance	12 bit modes f_{ADCK} < 4MHz	—	—	5	kΩ	5
f_{ADCK}	ADC conversion clock frequency	≤ 12 bit modes	1.0	—	18.0	MHz	6
f_{ADCK}	ADC conversion clock frequency	16 bit modes	2.0	—	12.0	MHz	6
C_{rate}	ADC conversion rate	≤ 12 bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	20.000	—	818.330	Ksps	7
C_{rate}	ADC conversion rate	16 bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	37.037	—	461.467	Ksps	7

1. Typical values assume V_{DDA} = 3.0 V, Temp = 25°C, f_{ADCK} = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. DC potential difference.
3. V_{REFH} is internally tied to V_{DDA}.
4. V_{REFL} is internally tied to V_{SSA}.
5. This resistance is external to MCU. The analog source resistance should be kept as low as possible in order to achieve the best results. The results in this datasheet were derived from a system which has <8 Ω analog source resistance. The R_{AS}/C_{AS} time constant should be kept to <1ns.
6. To use the maximum ADC conversion clock frequency, the ADHSC bit should be set and the ADLPC bit should be clear.

Table 27. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Symbol	Description	Conditions[1]	Min.	Typ.[2]	Max.	Unit	Notes
E_{FS}	Full-scale error	• 12 bit modes • <12 bit modes	— —	-4 -1.4	-5.4 -1.8	LSB[4]	$V_{ADIN} = V_{DDA}$ 5
E_Q	Quantization error	• 16 bit modes • 12 bit modes	— —	-1 to 0 —	— ±0.5	LSB[4]	
ENOB	Effective number of bits	16 bit single-ended mode • Avg=32 • Avg=4 12 bit single-ended mode • Avg=32 • Avg=1	 12.2 11.4 	 13.9 13.1 10.8 10.2	 — — — —	 bits bits bits bits	6
SINAD	Signal-to-noise plus distortion	See ENOB	6.02 × ENOB + 1.76			dB	
THD	Total harmonic distortion	16 bit single-ended mode • Avg=32 12 bit single-ended mode • Avg=32	 — —	 -85 -74	 — —	 dB dB	7
SFDR	Spurious free dynamic range	16 bit single-ended mode • Avg=32 12 bit single-ended mode • Avg=32	 78 	 90 78	 — —	 dB dB	7
E_{IL}	Input leakage error		$I_{In} \times R_{AS}$			mV	I_{In} = leakage current (refer to the device's voltage and current operating ratings)
	Temp sensor slope	–40°C to 105°C	—	1.715	—	mV/°C	
V_{TEMP25}	Temp sensor voltage	25°C	—	722	—	mV	8

1. All accuracy numbers assume the ADC is calibrated with $V_{REFH} = V_{DDA}$
2. Typical values assume V_{DDA} = 3.0 V, Temp = 25°C, f_{ADCK} = 2.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

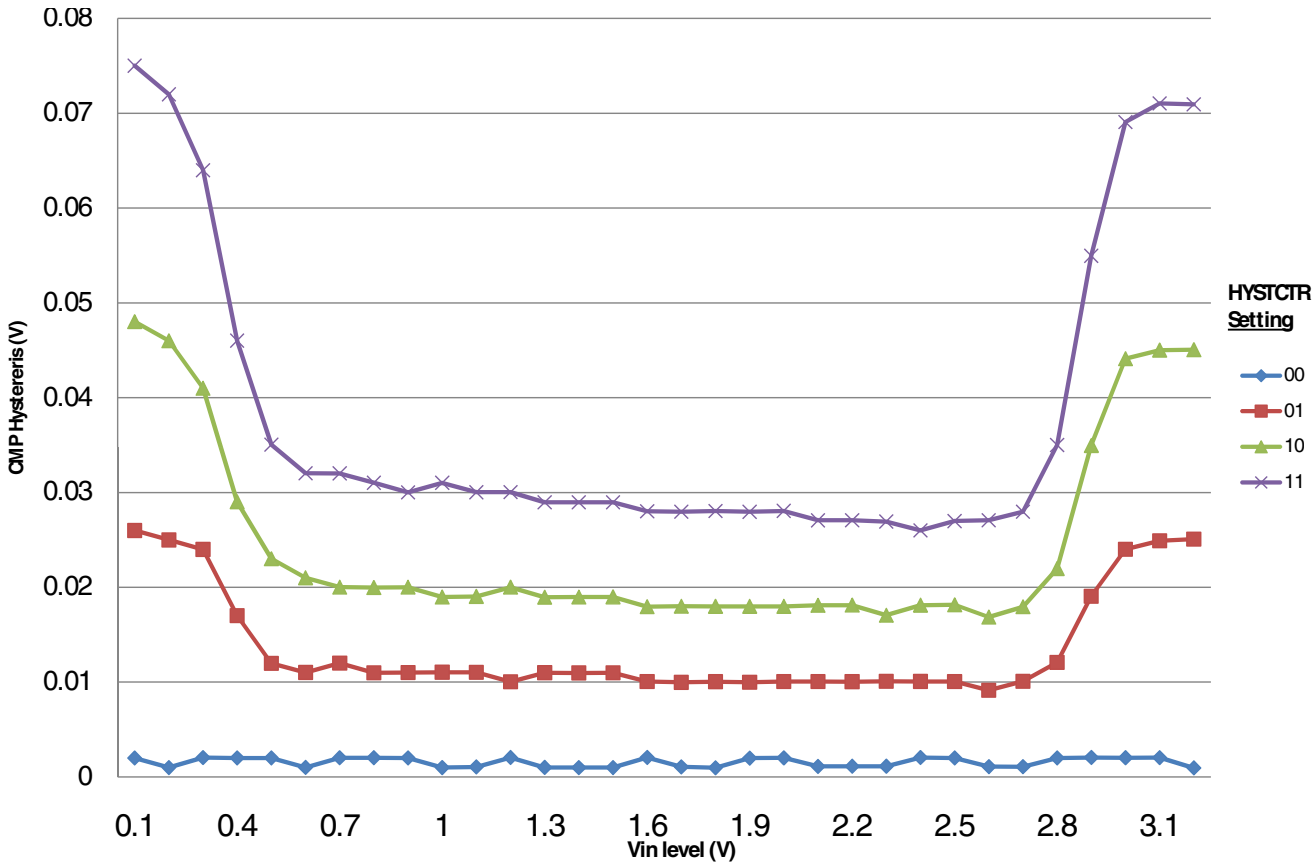

Figure 12. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 0)

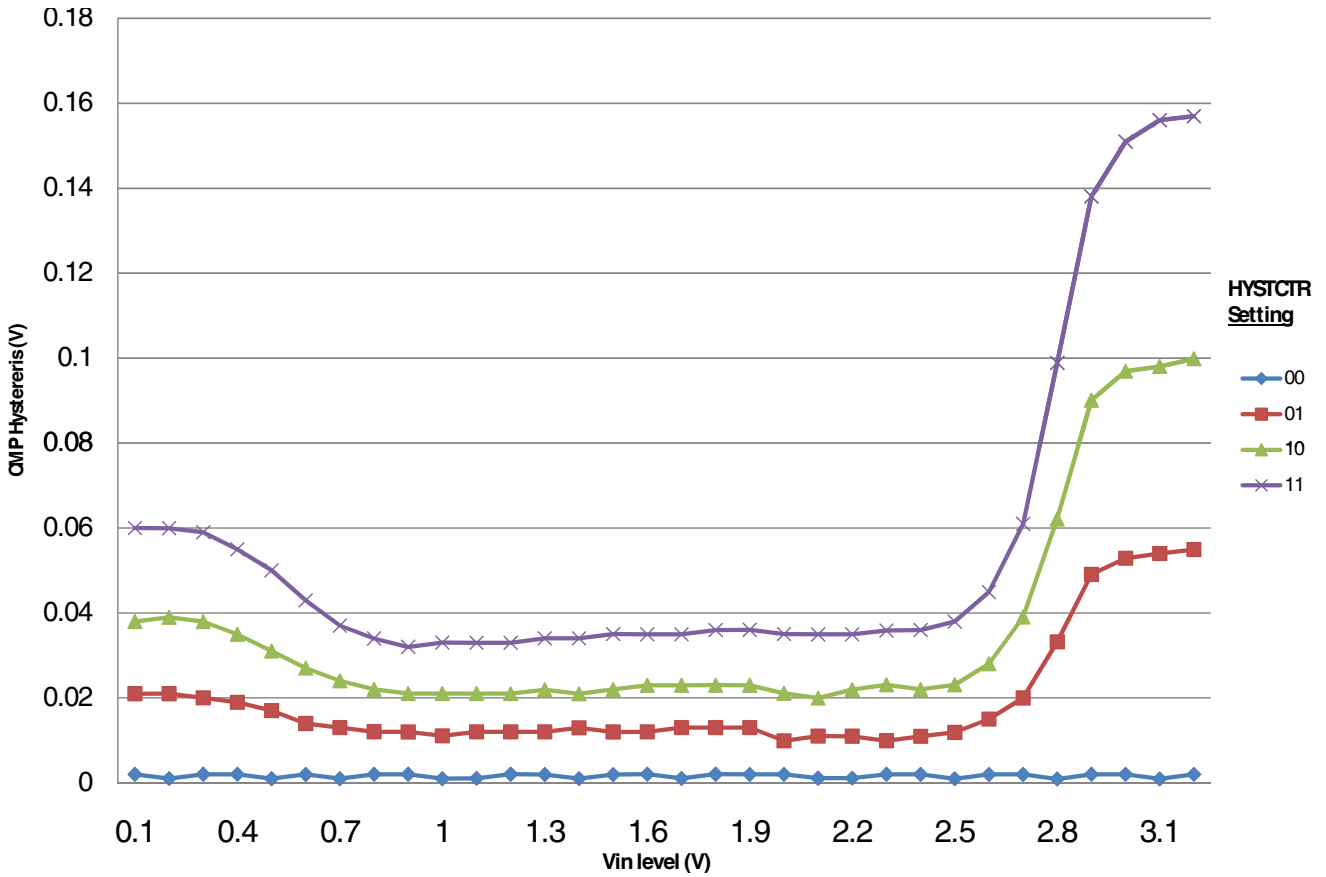

Figure 13. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 1)

8.6 PWMs and timers

8.6.1 PWM Characteristics

Table 30. PWM Timing Parameters

Characteristic	Symbol	Min	Typ	Max	Unit
PWM clock frequency			60	100	MHz

8.6.2 Quad Timer Timing

Parameters listed are guaranteed by design.

Table 32. SPI Timing (continued)

Characteristic	Symbol	Min	Max	Unit	See Figure
Clock (SCK) high time	t_{CH}				Figure 15
Master		27.6	—	ns	Figure 16
Slave		27.6	—	ns	Figure 17
					Figure 18
Clock (SCK) low time	t_{CL}				Figure 18
Master		27.6	—	ns	
Slave		27.6	—	ns	
Data set-up time required for inputs	t_{DS}				Figure 15
Master		27.6	—	ns	Figure 16
Slave		1	—	ns	Figure 17
					Figure 18
Data hold time required for inputs	t_{DH}				Figure 15
Master		1	—	ns	Figure 16
Slave		3	—	ns	Figure 17
					Figure 18
Access time (time to data active from high-impedance state)	t_A				Figure 18
Slave		5	—	ns	
Disable time (hold time to high-impedance state)	t_D				Figure 18
Slave		5	—	ns	
Data valid for outputs	t_{DV}				Figure 15
Master		—	8.3	ns	Figure 16
Slave (after enable edge)		—	25	ns	Figure 17
					Figure 18
Data invalid	t_{DI}				Figure 15
Master		0	—	ns	Figure 16
Slave		0	—	ns	Figure 17
					Figure 18
Rise time	t_R				Figure 15
Master		—	1	ns	Figure 16
Slave		—	1	ns	Figure 17
					Figure 18
Fall time	t_F				Figure 15
Master		—	1	ns	Figure 16
Slave		—	1	ns	Figure 17
					Figure 18

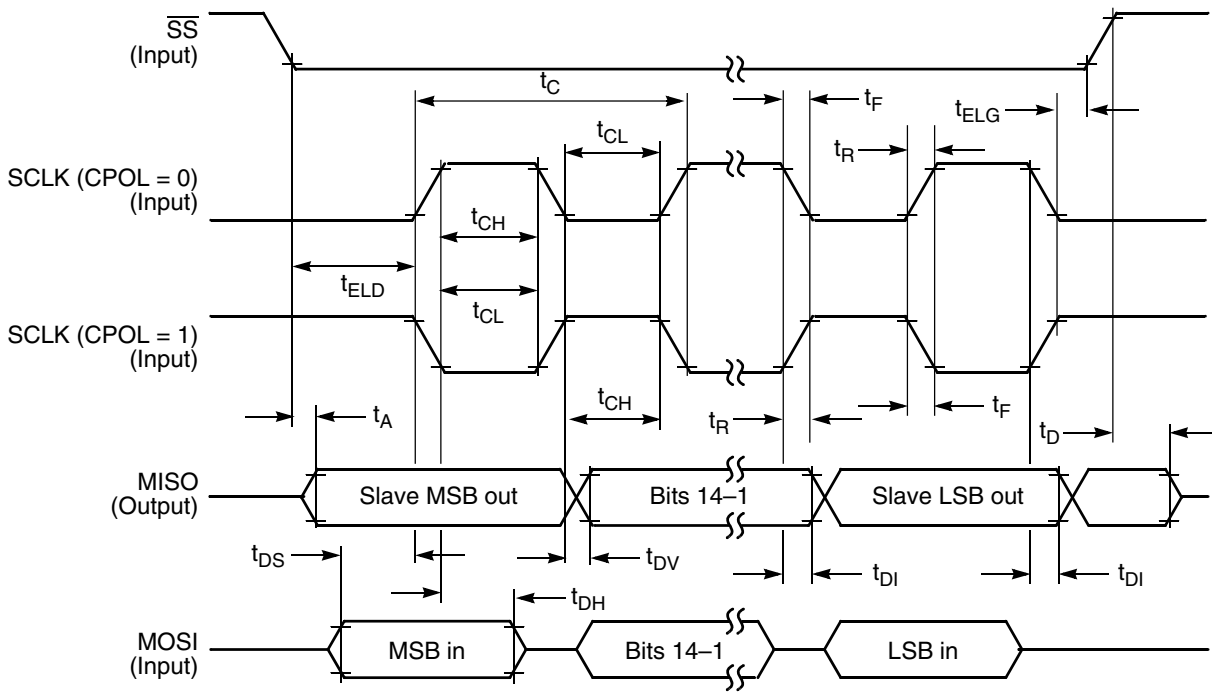

Figure 17. SPI Slave Timing (CPHA = 0)

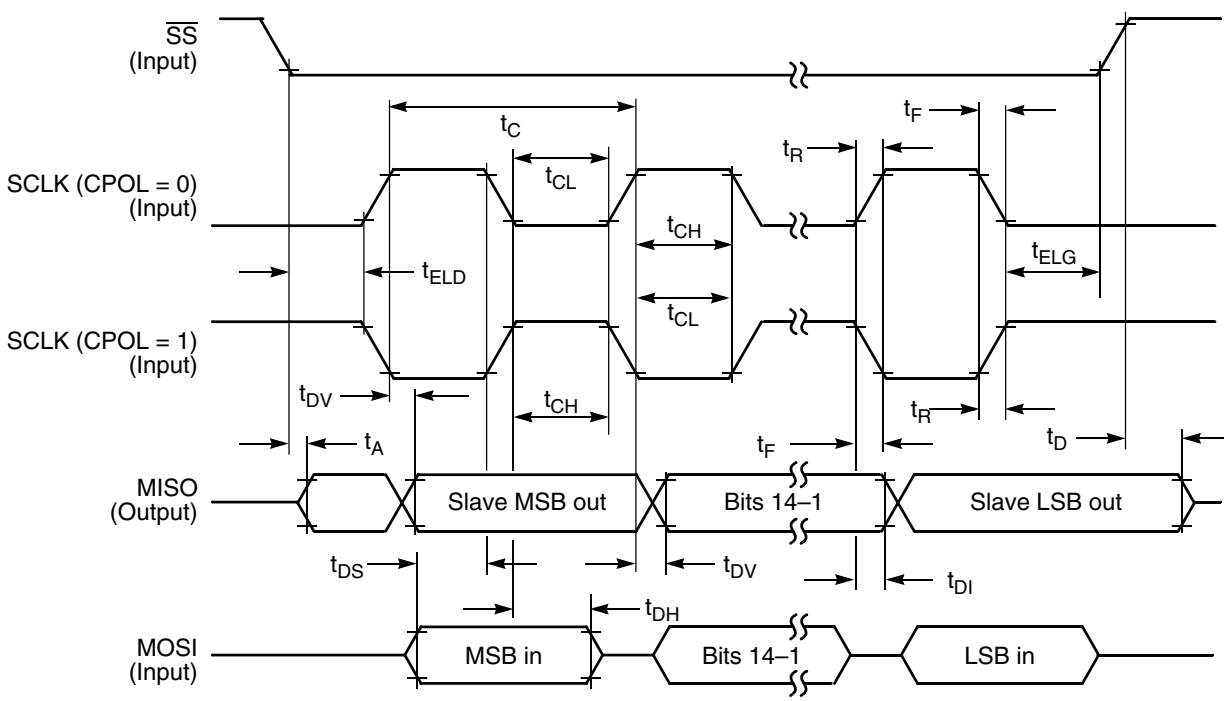

Figure 18. SPI Slave Timing (CPHA = 1)

8.7.2 Queued Serial Communication Interface (SCI) Timing

Parameters listed are guaranteed by design.

Table 33. SCI Timing

Characteristic	Symbol	Min	Max	Unit	See Figure
Baud rate[1]	BR	—	(f_{MAX}/16)	Mbps	—
RXD pulse width	RXD_{PW}	0.965/BR	1.04/BR	ns	Figure 19
TXD pulse width	TXD_{PW}	0.965/BR	1.04/BR	ns	Figure 20
LIN Slave Mode					
Deviation of slave node clock from nominal clock rate before synchronization	$F_{TOL\_UNSYNCH}$	-14	14	%	—
Deviation of slave node clock relative to the master node clock after synchronization	F_{TOL_SYNCH}	-2	2	%	—
Minimum break character length	T_{BREAK}	13	—	Master node bit periods	—
		11	—	Slave node bit periods	—

1. f_{MAX} is the frequency of operation of the SCI clock in MHz, which can be selected system clock (max. 120 MHz depending on part number) or 2x system clock (max. 200 MHz) for the devices.

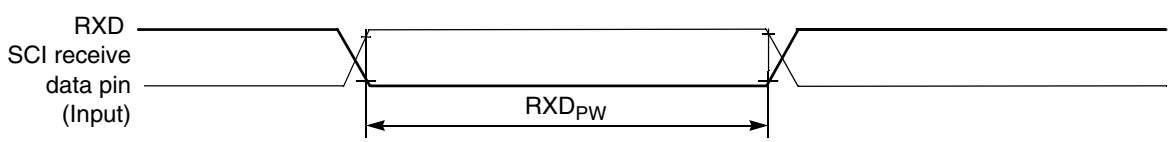

Figure 19. RXD Pulse Width

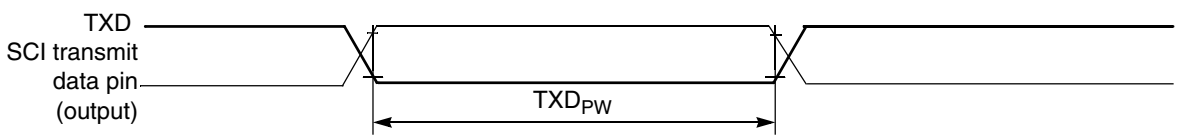

Figure 20. TXD Pulse Width

8.7.3 Freescale's Scalable Controller Area Network (FlexCAN)

Table 34. FlexCAN Timing Parameters

Characteristic	Symbol	Min	Max	Unit
Baud Rate	BR_{CAN}	—	1	Mbps
CAN Wakeup dominant pulse filtered	T_{WAKEUP}	—	2	µs
CAN Wakeup dominant pulse pass	T_{WAKEUP}	5	—	µs

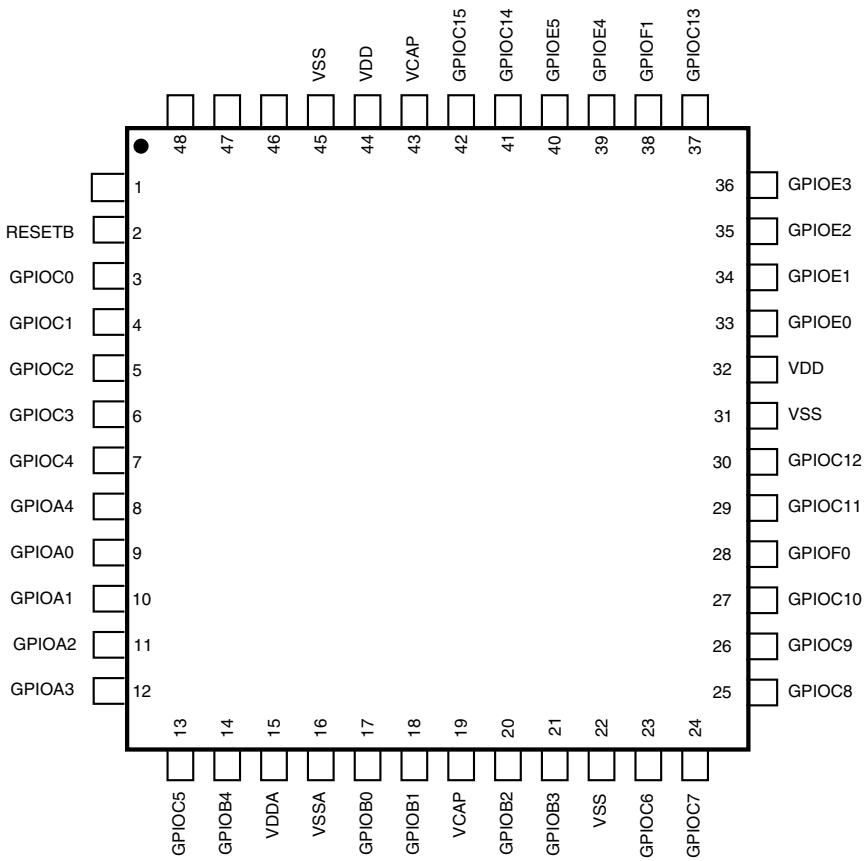

Figure 24. 48-pin LQFP

12 Product Documentation

The documents listed in Table 36 are required for a complete description and proper design with the device. Documentation is available from local Freescale distributors, Freescale Semiconductor sales offices, or online at http://www.freescale.com.

Table 36. Device Documentation

Topic	Description	Document Number
DSP56800E/DSP56800EX Reference Manual	Detailed description of the 56800EX family architecture, 32-bit digital signal controller core processor, and the instruction set	DSP56800ERM
MC56F844xx Reference Manual	Detailed functional description and programming model	MC56F844XXRM
Serial Bootloader User Guide	Detailed description of the Serial Bootloader in the DSC family of devices	TBD
MC56F844xx Data Sheet	Electrical and timing specifications, pin descriptions, and package information (this document)	MC56F844XX
MC56F84xxx Errata	Details any chip issues that might be present	MC56F84XXX_0N27E

13 Revision History

The following table summarizes changes to this document since the release of the previous version.

Table 37. Revision History

Rev.	Date	Substantial Changes
2	06/2012	This is the first publicly released version of this document.